

30V P-CHANNEL MOSFET

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Features

- Advanced engineering: Trench MOSFET technology
- Excellent Thermal Properties: Good thermal management
- Optimized efficiency: Low RDS(on) of 11mΩ reduces power losses
- Enhanced performance: High power density package
- Compact form factor: PDFN3333 package measures only 3.3mm x 3.3mm



Our advanced MOSFET: <u>MCG50P03B</u>, 30V P-channel component is meticulously engineered to deliver where space is at a premium, and reliable performance is a must.

Its compact PDFN333 package measures only 3mm x 3mm, providing high power density for challenging applications.





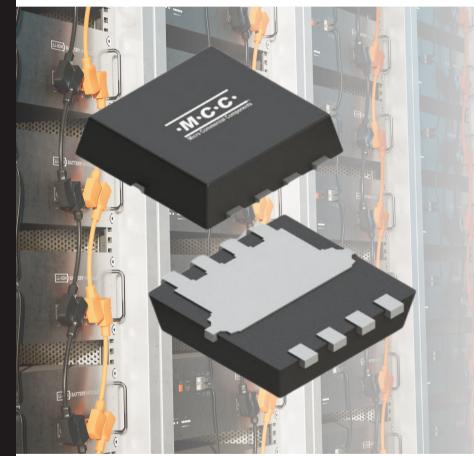
Management



Controls



30V P-Channel MOSFET: Get High Performance and High Power Density



Low RDS(on) and PDFN3333 Package Enable Excellence in Compact Applications

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Packed with power density and excellent thermal properties



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Product Attributes, Parametrics & Datasheets

Product	Туре	Package	Drain- SourceVoltage VDS	Drain- SourceOn- ResistanceRDS (ON)	Mounting Type	Datasheet
<u>MCG50P03B</u>	P-Channel Power MOSFET	PDFN3333	-30V	llmΩ	Surface-Mount (SMD)	<u>Info</u>

Applications:

Power Management	Motor Controls	Consumer Electronics	Industrial
 Battery management systems (BMS) DC-DC converters Power supply units (PSUs) 	 Motor drives Brushless DC (BLDC) motors Controllers Stepper motor drives 	Portable devicesPower adaptersCharging stations	 Robotics control systems Automation equipment Renewable energy systems (e.g., solar inverters)



